

# **CNC1S171** (ON3171)

## Optoisolator

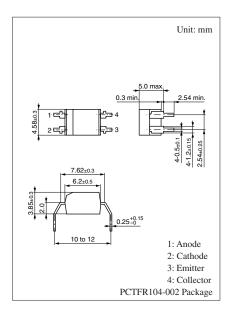
For isolated signal transmission

#### ■ Features

- High current transfer ratio: CTR > 50% UL listed (No. E79920)
- High I/O isolation voltage:
- BSI certified
- $V_{ISO} = 5 000 \text{ V[rms] (min.)}$
- (BS415 No. 7889, BS7002 No.7890)
- Fast response:
- SEMKO certified (No. 9625004)
- $t_r = 2 \mu s$ ,  $t_f = 3 \mu s$  (typ.) DEMKO certified (No. 305848)
- Low collector-emitter cutoff current NEMKO certified (No. 199633176)
- (Base open) :  $I_{CEO} < 100 \text{ nA}$
- FIMKO certified (No. 191784)
- VDE approved (VDE0884)
- CSA approved (No. CA109151)

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

-	Symbol	Rating	Unit	
Input (Light	Reverse voltage	Reverse voltage V <sub>R</sub> 6		V
emitting diode)	Forward current	$I_F$	50	mA
	Pulse forward current *1	$I_{FP}$	1	A
	Power dissipation *2	$P_{\mathrm{D}}$	75	mW
Output (Photo	Collector-emitter voltage	V <sub>CEO</sub>	80	V
transistor)	(Base open)			
	Emitter-collector voltage	V <sub>ECO</sub>	7	V
	(Base open)			
	Collector current	$I_{C}$	50	mA
	Collector power dissipation *3	P <sub>C</sub>	150	mW
Isolation voltage, input to output		V <sub>ISO</sub>	5 000	V[rms]
Total power di	P <sub>T</sub>	200	mW	
Operating amb	T <sub>opr</sub>	-30 to +100	°C	
Storage temper	T <sub>stg</sub>	-55 to +125	°C	



Note) \*1: Pulse width  $\leq 100 \,\mu s$ , repeat 100 pps

\*2: Input power derating ratio is  $0.75 \text{ mW/}^{\circ}\text{C}$  at  $T_a \ge 25^{\circ}\text{C}$ 

\*3: Output power derating ratio is 1.5 mW/°C at  $T_a \ge 25$ °C

#### ■ Electrical-Optical Characteristics $T_a = 25$ °C $\pm 3$ °C

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input	Forward voltage	V <sub>F</sub>	$I_F = 50 \text{ mA}$		1.35	1.50	V
characteristics	Reverse current	$I_R$	$V_R = 3 V$			10	μΑ
	Terminal capacitance	Ct	$V_R = 0 V, f = 1 MHz$		15		pF
Output characteristics	Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{C} = 100 \ \mu A$	80			V
	Emitter-collector voltage (Base open)	V <sub>ECO</sub>	$I_E = 10 \mu A$	7			V
	Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = 20 \text{ V}$		5	100	nA
	Collector-emitter capacitance	C <sub>C</sub>	$V_{CE} = 10 \text{ V, } f = 1 \text{ MHz}$		10		pF
Transfer	DC current transfer ratio *1, 4	CTR	$V_{CE} = 10 \text{ V}, I_F = 5 \text{ mA}$	50		600	%
characteristics	Isolation capacitance, input to output	C <sub>ISO</sub>	f = 1 MHz		0.7		pF
	Isolation resistance, input to output	R <sub>ISO</sub>	$V_{\rm ISO} = 500 \text{ V}$	1011			Ω
	Rise time *2	t <sub>r</sub>	$V_{CC} = 10 \text{ V}, I_{C} = 2 \text{ mA}$		2		μs
	Fall time *3	$t_{\rm f}$	$R_L = 100 \Omega$		3		μs
	Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_F = 20 \text{ mA}, I_C = 1 \text{ mA}$		0.1	0.2	V

Note) The part number in the parenthesis shows conventional part number.

Publication date: April 2004 SHF00003BED 1

#### ■ Electrical-Optical Characteristics (continued) $T_a = 25$ °C $\pm 3$ °C

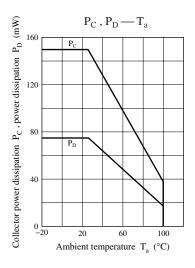
Note) 1. Input and output are handled electrically.

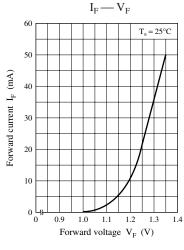
2. This product is not designed to withstand radiation

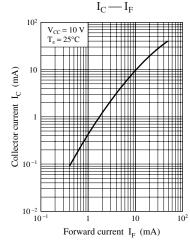
3. \*1: 
$$CTR = \frac{I_C}{I_F} \times 100\%$$

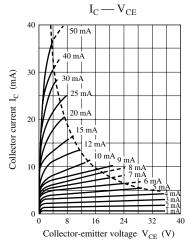
- $*2: t_r$ ; Time required for the collector current to increase from 10% to 90% of its final value
- $*3: t_f$ ; Time required for the collector current to decrease from 90% to 10% of its initial value
- \*4: Rank classification

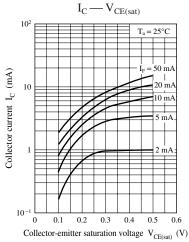
_	Rank	Q	R	S	No-rank
	CTR (%)	50 to 120	100 to 250	200 to 600	50 to 600

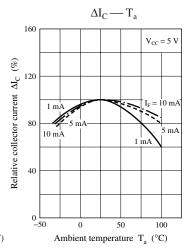




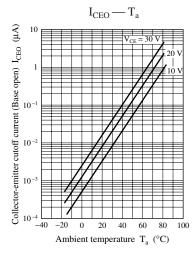


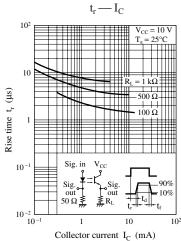


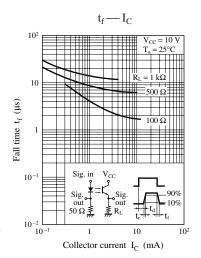




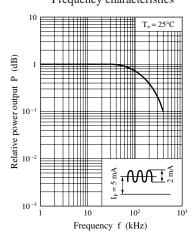
## **Panasonic**



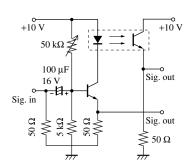




Frequency characteristics



Measurement circuit of frequency characteristics



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